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**Investigation of phase composition and microwave dielectric properties of  
MgO-Ta<sub>2</sub>O<sub>5</sub> ceramics with ultra-high Qf value**

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**Abstract:** Four MgO-Ta<sub>2</sub>O<sub>5</sub> ceramics with the MgO/Ta<sub>2</sub>O<sub>5</sub> mole ratio x=1, 2, 3 and 4  
were prepared by traditional solid state reaction method, and the influence of x on

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the phase composition, microstructure and dielectric properties (the dielectric constant  $\epsilon_r$ , the temperature coefficient of resonant frequency  $\tau_f$  and the quality factor  $Q_f$ ) of the materials was investigated by using XRD, SEM, etc. The results indicated that the ceramics were composed of two crystalline phases  $\text{MgTa}_2\text{O}_6$  and  $\text{Mg}_4\text{Ta}_2\text{O}_9$  in the composition range studied, and that the dielectric properties  $\ln \epsilon$ ,  $1/Q_f$  and  $\tau_f$  changed proportionally to the fraction of main crystal phases, which meet perfectly with the mixing model proposed in this study. It is obvious that the proportion of the two crystal phases could be precisely controlled by  $x$ , and thereby, the dielectric properties can be conveniently and precisely tailored. Our research provided a new microwave dielectric ceramic with the composition of  $2\text{MgO-Ta}_2\text{O}_5$ , which has an ultra-high  $Q_f$  value (211 000 GHz), low dielectric constant  $\epsilon_r$  (19.9) and near zero temperature coefficient of resonant frequency  $\tau_f$  (8 ppm/°C).

**Keywords:** MgO-Ta<sub>2</sub>O<sub>5</sub> ceramics; microwave dielectric properties; ultra-high quality factor

## 1. Introduction

Nowadays, low permittivity ( $\epsilon_r=6-20$ ) and high quality factor ( $Q_f>75\ 000$  GHz) microwave dielectric ceramics which are mainly used in the areas of millimeter-wave communications have generated considerable research interest because of the fast

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development of mobile communications, satellite communications and intelligent transportation systems etc.<sup>1, 2</sup>. It was expected that  $\text{ZnAl}_2\text{O}_4$ - $\text{TiO}_2$ -,  $\text{Mg}_4\text{Ta}_2\text{O}_9$ -,  $\text{Mg}_2\text{SiO}_4$ - and  $\text{Al}_2\text{O}_3$ -based materials were some examples for possible applications in millimeter-wave communications<sup>3</sup>. However, these materials did not have the near zero temperature coefficient of resonant frequency ( $\tau_f \approx 0$  ppm/°C) which was demanded in that application field. Unfortunately, satisfying the three properties simultaneously was very difficult.

It has been reported that some Ta-containing microwave dielectric ceramics have high Qf values due to the high covalencies of Ta-O bonds, such as  $\text{Ba}(\text{Mg}_{1/3}\text{Ta}_{2/3})\text{O}_3$ <sup>4</sup>,  $\text{Ba}(\text{Zn}_{1/3}\text{Ta}_{2/3})\text{O}_3$ <sup>5</sup>,  $\text{MgZrTa}_2\text{O}_8$ <sup>6</sup>,  $\text{Mg}_4\text{Ta}_2\text{O}_9$ <sup>7</sup>, et al. Because of the low permittivity of  $\text{Mg}_4\text{Ta}_2\text{O}_9$ , numerous investigations have established to make the  $\text{Mg}_4\text{Ta}_2\text{O}_9$ -based ceramics satisfy the performance mentioned above. In 2007, Kan et al.<sup>7</sup> first reported the  $\text{Mg}_4\text{Ta}_2\text{O}_9$  ceramics with corundum's structure and excellent microwave dielectric properties:  $\epsilon_r=10$ ,  $\text{Qf}=345\ 000$  GHz,  $\tau_f=-70$  ppm/°C. But its  $\tau_f$  is so negative that it cannot be applied. Kim<sup>8, 9</sup> provided a method to obtain the near zero  $\tau_f$  ceramics ( $\epsilon_r=14.8$ ,  $\text{Qf}=102\ 100$  GHz,  $\tau_f=3.86$  ppm/°C) by mixing the positive  $\tau_f$  ceramic phase  $\text{TiO}_2$  and negative phase  $\text{Mg}_4\text{Ta}_2\text{O}_9$  with the ratio of 1:1. However they pointed out that  $\text{TiO}_2$  would interact with  $\text{Mg}_4\text{Ta}_2\text{O}_9$  to form  $\text{MgTi}_2\text{O}_5$  etc. which hindered the enhancement of Qf values of the composite ceramics. Similar results also occurred in  $\text{Mg}_4\text{Nb}_2\text{O}_9$  ceramics<sup>10, 11</sup>. Thus it is very important to choose the proper positive  $\tau_f$  material to prevent new phases with low Qf values synthesized during tailoring the  $\tau_f$ . The binary phase diagram of  $\text{MgO}$ - $\text{Ta}_2\text{O}_5$ <sup>12</sup> indicates that

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MgTa<sub>2</sub>O<sub>6</sub> with trirutile-type structure is another stable phase which can co-exist with Mg<sub>4</sub>Ta<sub>2</sub>O<sub>9</sub>. Moreover, it possesses high Q<sub>f</sub> values (Q<sub>f</sub>=59 600 GHz)<sup>13, 14</sup> and positive  $\tau_f$  ( $\tau_f$ =30 ppm/°C). These properties are very beneficial for adjusting the  $\tau_f$  to near zero and guaranteeing the Q<sub>f</sub> values of ceramics. Some attentions have been paid to the selection of MgTa<sub>2</sub>O<sub>6</sub> as a  $\tau_f$  controlling material<sup>10, 14</sup>.

In this paper, the phase composition and microstructures of ceramics which were obtained from xMgO-Ta<sub>2</sub>O<sub>5</sub> (x=1, 2, 3, 4) system were studied, and then the relationships between the phase composition and microwave dielectric properties were carefully analyzed and discussed.

## 2. Experimental Procedure

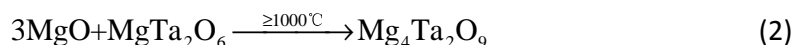
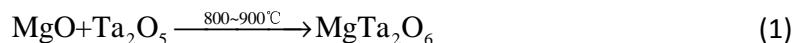
High purity (≥99.9%) MgO (calcined at 800 °C for 4 h) and Ta<sub>2</sub>O<sub>5</sub> powders were weighed according to the stoichiometric ratio of xMgO-Ta<sub>2</sub>O<sub>5</sub> and noted as xMT (x=1, 2, 3, 4), adding with 0.5 wt% B<sub>2</sub>O<sub>3</sub> and then mixed in deionized water for 1 h with zirconia balls as milling media. The mixtures were dried and then calcined at 800~1200 °C for 8 h in air. The calcined powders were re-milled and ground with polyvinyl alcohol. The granules were pressed into pellets (Φ10 mm×5 mm) under a pressure of 100 MPa and then the pellets were sintered to get the ceramic samples at 1275 °C~1600 °C for 4 h in air.

The bulk densities of the xMT ceramic samples were measured by the Archimedes method. The crystalline phase of the powders and the ceramics were identified by XRD (BRUKER AXS GMBH, Germany) using Cu K $\alpha$  radiation operated at 40 kV and 40 mA. The scanning electron microscopy (SEM; Magellan 400, FEI, American) with an energy dispersive spectrometer (EDS, Bruker) and an electron back scattered diffraction (EBSD, Oxford) were employed to examine the morphology of ceramics. The dielectric properties of samples were tested by Agilent E8362B network analyzer by the TE<sub>016</sub> mode dielectric resonator method<sup>15</sup>, and the  $\tau_f$  was obtained from the resonant frequencies which were measured at 25 °C and 85 °C.

### 3. Results and discussion

In order to study the solid reaction and phase transformation processes of the xMT (x=1, 2, 3, 4) powders, all the four powders were calcined at the temperature from 800~1200 °C for 8 h, and X-ray diffraction analysis of all samples was taken. As an example, Fig. 1 shows the XRD patterns of 4MT powder calcined at different temperatures. It can be found from the figure that the reaction process of MgO with Ta<sub>2</sub>O<sub>5</sub> could be divided into two phases. First one, when T<1000 °C, MgO reacted with Ta<sub>2</sub>O<sub>5</sub> to form MgTa<sub>2</sub>O<sub>6</sub>, and then the second, with the increase of temperature (T $\geq$ 1000 °C), the formed MgTa<sub>2</sub>O<sub>6</sub> further reacted with the surplus MgO to form a new phase of Mg<sub>4</sub>Ta<sub>2</sub>O<sub>9</sub>. The whole process can be expressed by the following equations:

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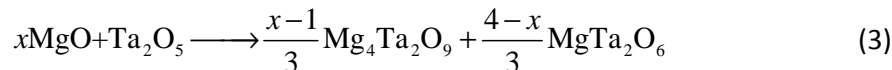


Besides, there were still some remaining  $\text{MgTa}_2\text{O}_6$  which has not been reacted with  $\text{MgO}$  in the synthesis process, which is in general agreement with Reference<sup>16</sup>. Therefore, all sintered ceramic samples were obtained from the powders calcined at  $1100^\circ\text{C}$  for 8 h in this study.

Fig. 2 shows the relative density of xMT ( $x=1, 2, 3, 4$ ) ceramics as a function of sintering temperature. It can be seen that the maximum density was acquired at  $1550^\circ\text{C}$  for the sample MT ( $x=1$ ) and the ones for the samples 2MT, 3MT and 4MT ( $x=2, 3, 4$ ) were obtained at around  $1325^\circ\text{C}$  (more details are listed in Table 1). Then, XRD patterns of xMT ceramics sintered at optimum temperature are illustrated in Fig. 3. It was found that there were three crystalline phases, the two main phases  $\text{MgTa}_2\text{O}_6$ ,  $\text{Mg}_4\text{Ta}_2\text{O}_9$ , and the slight  $\text{Mg}_5\text{TaO}_3(\text{BO}_3)_3$ , besides, the content of  $\text{Mg}_4\text{Ta}_2\text{O}_9$  increased with the increasing of  $x$ . In order to quantitatively analyze the relative percentage of  $\text{MgTa}_2\text{O}_6$  and  $\text{Mg}_4\text{Ta}_2\text{O}_9$ , the Rietveld Analysis method in GSAS 2.0 was employed using the ICSD No.79-0380 and No.84-1679 as standard references. The results are given in Table 2. Meanwhile, from reaction (1) and (2), it can be concluded that the reaction of  $\text{MgO}$  with  $\text{Ta}_2\text{O}_5$  when samples are with different  $\text{MgO}/\text{Ta}_2\text{O}_5$  mole ratio  $x$  could be written as equation (3). Then, the theoretical quantitative percentage of  $\text{Mg}_4\text{Ta}_2\text{O}_9$  was calculated and the results are also listed in Table 2. It can be seen that the theoretical values were very close to that calculated

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from Jade. Hence, it is apparent that the phase content of  $\text{Mg}_4\text{Ta}_2\text{O}_9$  can be controlled by the  $\text{MgO}/\text{Ta}_2\text{O}_5$  mole ratio  $x$ .



The SEM images of ceramic samples with different  $x$  and sintered at the optimum temperatures were displayed in Fig. 4. Two phases  $\text{MgTa}_2\text{O}_6$  (grey) and  $\text{Mg}_4\text{Ta}_2\text{O}_9$  (black) had been clearly seen in the figure, which were identified by EDS spectrum and XRD diffraction. Interestingly, although both MT and 4MT were highly densified (>95%), their grain size was not uniform which could distribute from 7  $\mu\text{m}$  to 37  $\mu\text{m}$  and 4MT even contented some closed pores. Furthermore, as evident in Fig. 4b and Fig. 4c, when two phases co-existed in the samples, the grain size of each phase was less than 8  $\mu\text{m}$ . It might be reasonable to assume that two phases had the similar grain growth rate at the same temperature and thermodynamic stability. So the grain size was decreased by their contest. When their content was close to each other, the inhibitory effect is more obvious. The EBSD phase map of 2MT ceramic (Fig. 5) was also collected to confirm distribution and fraction of different phases. It was evident that there were two main phases  $\text{Mg}_4\text{Ta}_2\text{O}_9$  and  $\text{MgTa}_2\text{O}_6$  which were randomly distributed in 2MT ceramic and the fraction of  $\text{Mg}_4\text{Ta}_2\text{O}_9$  was 35% which was very close to the theoretical values 38.5%.

The optimum microwave dielectric properties of samples were given in Table 1. It can be found that the 2MT sample has very excellent dielectric properties, which

could be applied in millimeter-wave communications, through the microwave dielectric properties comparison of the materials with similar permittivity in Table 3.

It is also known from the literature<sup>17</sup> that the dielectric properties of mixture phases of two compounds can be predicted by some empirical models. The models are given below:

$$\ln \varepsilon = V_1 \ln \varepsilon_1 + V_2 \ln \varepsilon_2 \quad (4)$$

$$\tau_f = V_1 \tau_{f1} + V_2 \tau_{f2} \quad (5)$$

$$\frac{1}{Q} = \frac{V_1}{Q_1} + \frac{V_2}{Q_2} \quad (6)$$

where  $V_1$ ,  $V_2$ ,  $\varepsilon_1$ ,  $\varepsilon_2$ ,  $\tau_{f1}$ ,  $\tau_{f2}$ ,  $Q_1$  and  $Q_2$  are the volume fractions, permittivity, temperature coefficient of resonant frequency and quality factors of the two components, while  $\varepsilon$ ,  $\tau_f$  and  $Q$  are the resultant of the mixture. As we all know, it is predicted from the classical dispersion theory that the dielectric loss increases proportionately with frequency at microwave frequency<sup>5, 18</sup>. Therefore the  $Qf$  value which is inherent in each material is a constant, so the equality (6) can be rewritten as:

$$\frac{1}{Qf} = \frac{V_1}{Q_1 f_1} + \frac{V_2}{Q_2 f_2} \quad \text{or} \quad \frac{1}{Qf} = \frac{V_1}{C_1} + \frac{V_2}{C_2} \quad (7)$$

where the  $C_1$  and  $C_2$  are a constant value of phase 1 and phase 2. It should be noted that the measured  $\varepsilon_r$  should be corrected for porosity to get the actual permittivity of the material. The following equation was used in this work<sup>19</sup>:

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$$\varepsilon_r = \varepsilon \left( 1 - \frac{3P(\varepsilon - 1)}{2\varepsilon + 1} \right) \quad (8)$$

where P is the fractional porosity and others symbol have been mentioned above. In order to further verify the empirical models, variations of  $\ln \varepsilon$ ,  $1/Qf$ ,  $\tau_f$  as a function of the volume fraction of  $\text{Mg}_4\text{Ta}_2\text{O}_9$  in the xMT ceramics were shown in Fig. 6. It can be seen that the values located near a straight line, which indicates that this mixture perfectly meet the mixing models. So, it is obvious that the dielectric properties can be conveniently and precisely tailored by this method.

#### 4. Conclusions

In summary, the influence of x on the phase composition, microstructure and dielectric properties in  $\text{xMgO-Ta}_2\text{O}_5$  (xMT, x=1, 2, 3, 4) ceramics was investigated. The results indicated that the ceramics were composed of two crystalline phases  $\text{MgTa}_2\text{O}_6$  and  $\text{Mg}_4\text{Ta}_2\text{O}_9$  in the composition range studied, and that the dielectric properties  $\ln \varepsilon$ ,  $1/Qf$  and  $\tau_f$  changed proportionally to the fraction of main crystal phases. This result provided compelling evidence that the proportion of the two crystal phases could be precisely controlled by x, and thereby, the dielectric properties can be conveniently and precisely tailored. Our study also provided an ultra-high Qf value ( $Qf=211\,000\text{ GHz}$ ,  $\varepsilon_r=19.9$ ,  $\tau_f=8\text{ ppm/}^\circ\text{C}$ ) materials  $2\text{MgO-Ta}_2\text{O}_5$  ceramic.

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**Table 1.** Microwave characteristics of xMT ceramics.

x values	Sintering temperature (°C)	Bulk density (g/cm <sup>3</sup> )	Dielectric properties		
			$\epsilon_r$	Qf (GHz)	$\tau_f$ (ppm/°C)
1	1550	7.56	28.0	188000	54
2	1325	6.83	19.9	211000	8
3	1325	6.39	15.2	230000	-31
4	1325	6.03	12.2	261000	-68

**Table 2.** Comparison of calculated and theoretical values of xMT ceramics.

x values	The Stoichiometric coefficients of Mg <sub>4</sub> Ta <sub>2</sub> O <sub>9</sub>	The mass fraction of Mg <sub>4</sub> Ta <sub>2</sub> O <sub>9</sub>		The volume fraction of Mg <sub>4</sub> Ta <sub>2</sub> O <sub>9</sub>	Theoretical density (g/cm <sup>3</sup> )
		Calculation from GSAS 2.0 (%)	Theoretical values (%)		
1	0	0.0	0.0	0.0	7.80
2	1/3	37.7	38.5	44.1	7.09
3	2/3	68.9	71.4	75.9	6.57
4	1	96.0	100.0	100.0	6.18

**Table 3.** Microwave dielectric properties comparison of the materials with similar permittivity.

No.	Composition	$\epsilon_r$	Qf (GHz)	$\tau_f$ (ppm/°C)	Ref.
1	0.23MgTiO <sub>3</sub> -0.77 (0.5ZnAl <sub>2</sub> O <sub>4</sub> -0.5TiO <sub>2</sub> )	18.7	190000	-1.8	20
2	Ba(Mg <sub>1/3</sub> Ta <sub>2/3</sub> )O <sub>3</sub>	25	180000	2.7	4
3	0.93(0.99Mg <sub>2</sub> TiO <sub>4</sub> -0.01Co <sub>2</sub> TiO <sub>4</sub> )-0 .07CaTiO <sub>3</sub>	17	105000	-5	21
4	Ba <sub>1.94</sub> La <sub>0.04</sub> (Mg <sub>1/2</sub> W <sub>1/2</sub> )O <sub>3</sub>	20	87680	-1.2	22
5	2MgO-Ta <sub>2</sub> O <sub>5</sub> +0.5 wt% B <sub>2</sub> O <sub>3</sub>	19.9	211000	8	Presente d

**Fig. 1.** XRD patterns of 4MT powders calcined at different temperatures.

**Fig. 2.** Relative density of xMT ceramics as a function of sintering temperature.

**Fig. 3.** XRD patterns of xMT ceramics sintered at optimum temperature.

**Fig. 4.** The typical microstructures of xMT ceramics at optimum sintering temperature. ① $\text{MgTa}_2\text{O}_6$  and ② $\text{Mg}_4\text{Ta}_2\text{O}_9$ .

**Fig. 5.** EBSD phase map of 2MT ceramic showing phase distribution and fraction.

**Fig. 6.** Variation of  $\ln \epsilon$ ,  $1/Qf$ ,  $\tau_f$  as a function of volume fraction of  $\text{Mg}_4\text{Ta}_2\text{O}_9$  in the xMT ceramics.

